

$$Z_{\text{total}} = R + i\omega L - \frac{i}{\omega C}$$

$$= R + i\left(\omega L - \frac{1}{\omega C}\right)$$

$$\tilde{I} = \frac{V_{\text{in}}}{Z_{\text{total}}} = \frac{V_p e^{i\omega t}}{R + i\left(\omega L - \frac{1}{\omega C}\right)} * \frac{R - i\left(\omega L - \frac{1}{\omega C}\right)}{R - i\left(\omega L - \frac{1}{\omega C}\right)}$$

$$= \frac{V_p e^{i\omega t} \left[R - i\left(\omega L - \frac{1}{\omega C}\right) \right]}{R^2 + \left(\omega L - \frac{1}{\omega C}\right)^2}$$

$$\operatorname{Re}(\tilde{I}) = \frac{V_p R}{R^2 + \left(\omega L - \frac{1}{\omega C}\right)^2}$$

$$\operatorname{Im}(\tilde{I}) = \frac{-V_p \left(\omega L - \frac{1}{\omega C}\right)}{R^2 + \left(\omega L - \frac{1}{\omega C}\right)^2}$$

$$\phi_{\tilde{I}} = \tan^{-1} \left(\frac{\operatorname{Im}(\tilde{I})}{\operatorname{Re}(\tilde{I})} \right)$$

Assume $R = 50 \Omega$ $\omega L = 100 \Omega$

$$\frac{1}{\omega C} = 50 \Omega$$

$$Z_{\text{total}} = 50 + i50$$

$$I \approx \frac{V_p e^{i\omega t} (50 - i50)}{5000} = \frac{V_p}{100} e^{i\omega t} (1 - i)$$

$$= \frac{\sqrt{2} V_p}{100} e^{i\omega t} \left(\frac{1 - i}{\sqrt{2}} \right)$$

$$\tilde{I} = \frac{\sqrt{2} V_p}{100} e^{i(\omega t - \frac{\pi}{4})}$$

For each element

$$V_R = \tilde{I} R, \quad V_C = \tilde{I} Z_C, \quad V_L = \tilde{I} Z_L$$

$$V_R = \frac{\sqrt{2} V_p}{2} e^{i(\omega t - \frac{\pi}{4})}$$

$$\begin{aligned}
 V_c &= \tilde{I} \frac{-i}{\omega C} \\
 &= \frac{\sqrt{2} V_p (50)}{100} e^{i(\omega t - \pi/4)} (-i) \\
 &= \frac{\sqrt{2} V_p}{2} e^{i(\omega t - \pi/4)} e^{-i\pi/2} \\
 &= \frac{\sqrt{2} V_p}{2} e^{i(\omega t - \frac{3\pi}{4})}
 \end{aligned}$$

$$\begin{aligned}\tilde{V}_L &= \tilde{I} Z_L = \tilde{I} (i100) \\ &= \frac{\sqrt{2} V_p (100)}{100} e^{i(\omega t - \pi/4)} e^{i\pi/2} \\ &= \sqrt{2} V_p e^{i(\omega t + \pi/4)}\end{aligned}$$

Refer to attached (or nearby)
"phasor" diagram

KVL:

$$\tilde{V}_{in} - \tilde{V}_L - \tilde{V}_C - V_R = 0 \quad (\text{Ignore } e^{i\omega t})$$

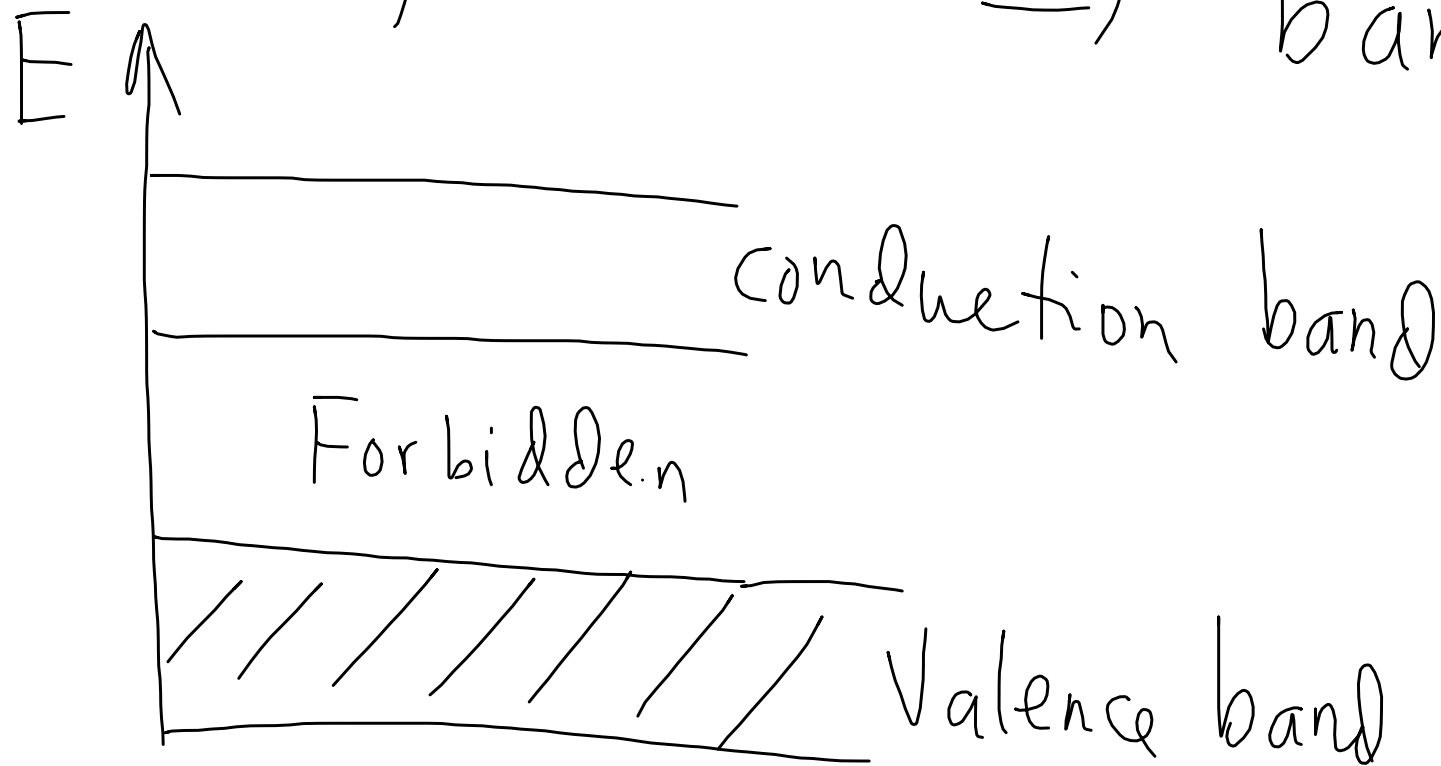
Go to real space (\hat{i} & \hat{j})
(consider $t=0$)

$$\cancel{V_p} \hat{i} - (\cancel{V_p} \hat{i} + \cancel{V_p} \hat{j}) - \left(-\frac{\cancel{V_p}}{2} \hat{i} - \frac{\cancel{V_p}}{2} \hat{j} \right) - \left(\frac{\cancel{V_p}}{2} \hat{i} - \frac{\cancel{V_p}}{2} \hat{j} \right) \stackrel{?}{=} 0 \quad \checkmark$$

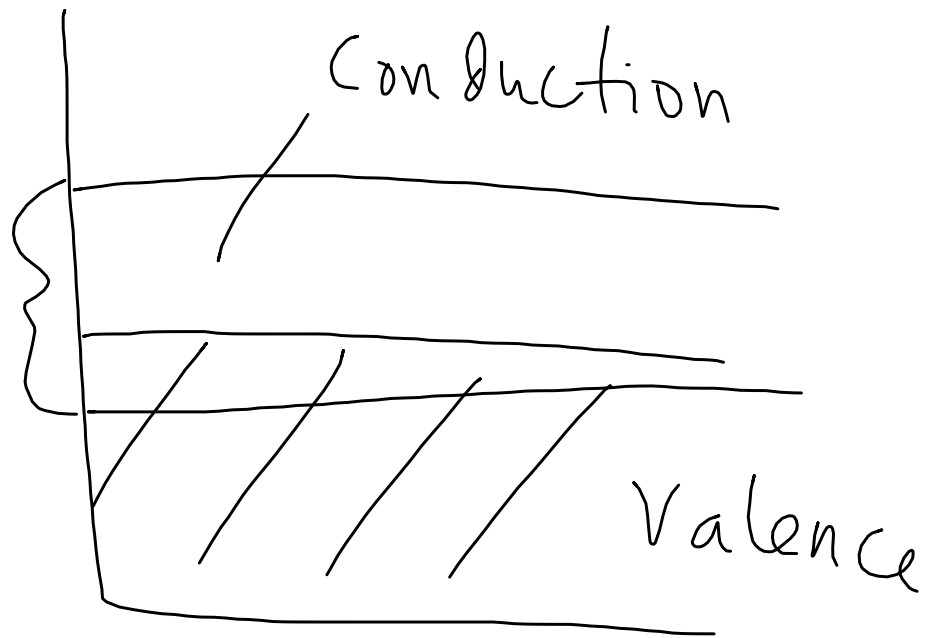
Diodes (but first, some SS physics)

Start from atoms \Rightarrow quantum energy levels

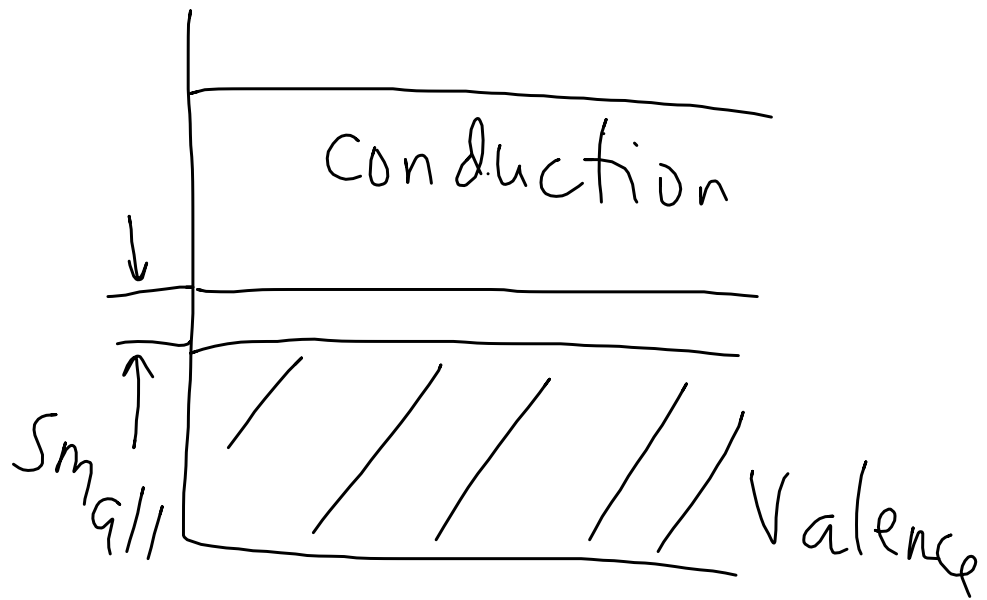
single levels \Rightarrow "bands"



This is picture for insulators

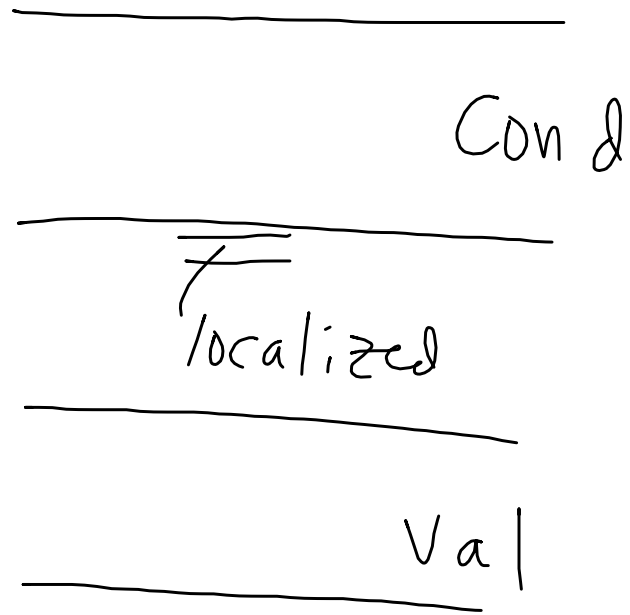


conductor



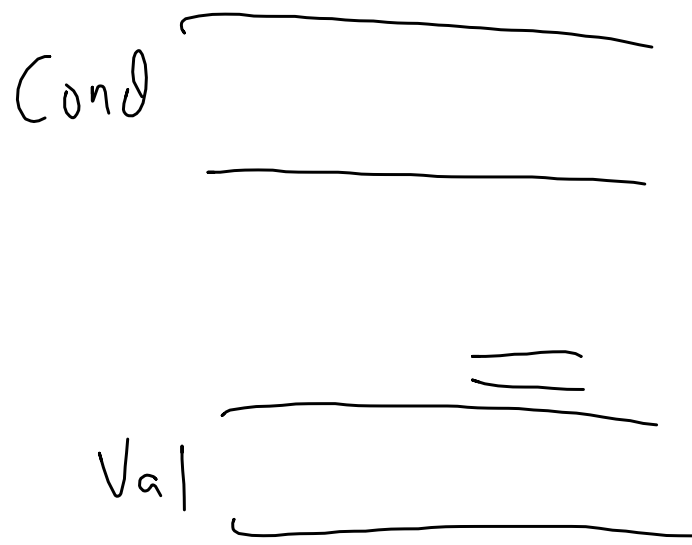
Semi-conductor

not good enough



As \Rightarrow 5 val. e^-

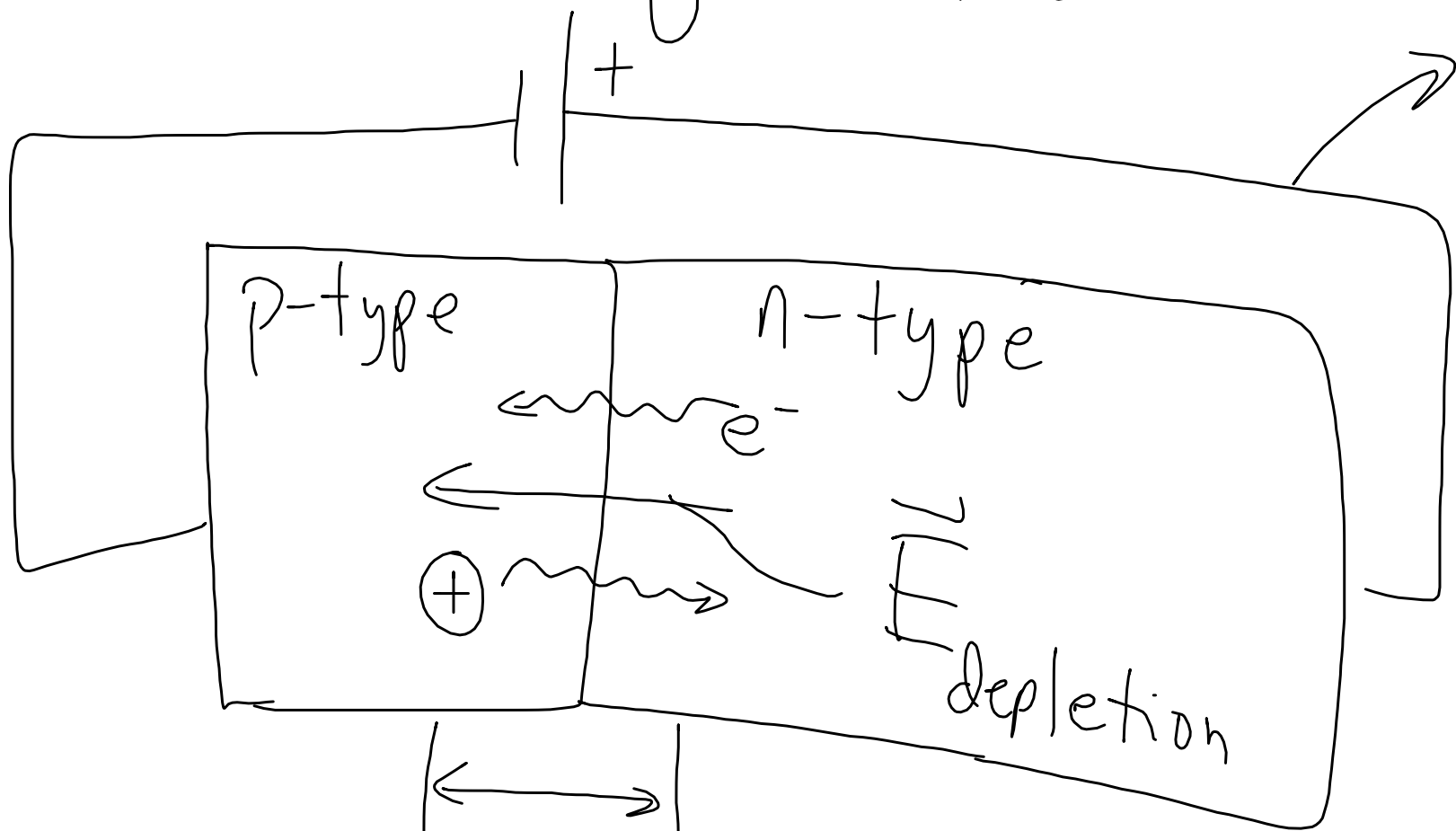
n-type doping



B₀ \Rightarrow 3 val e^-

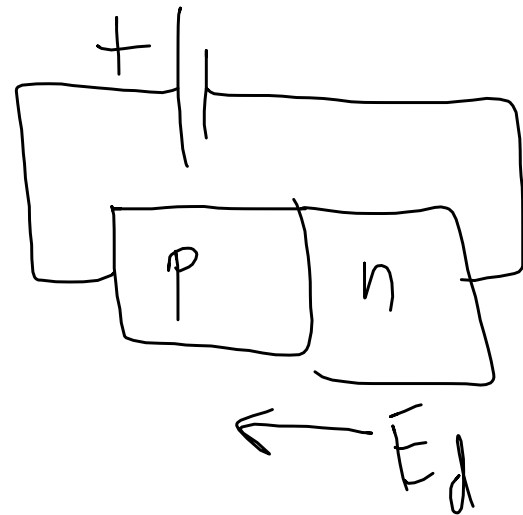
p-type

Make a junction

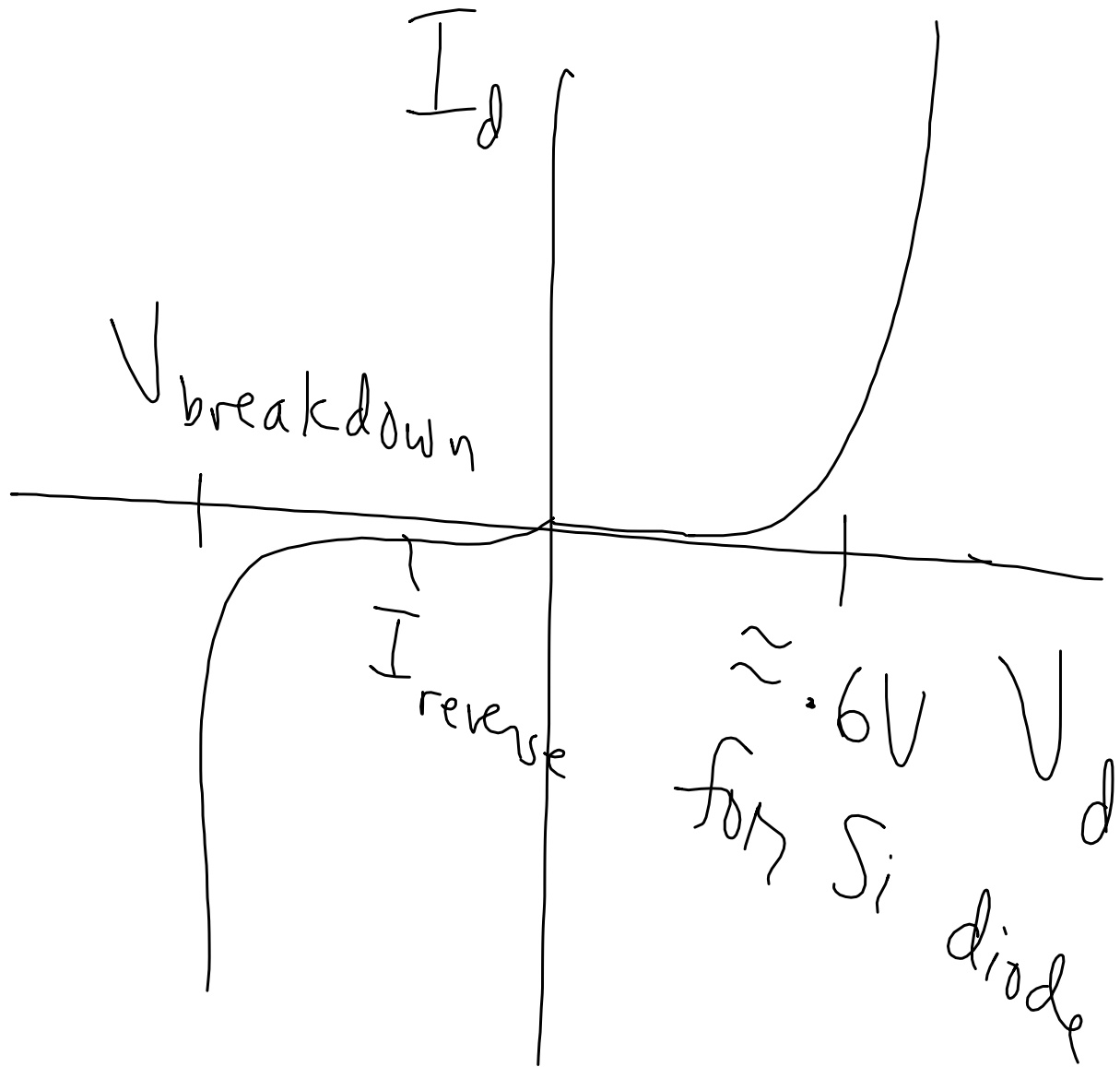
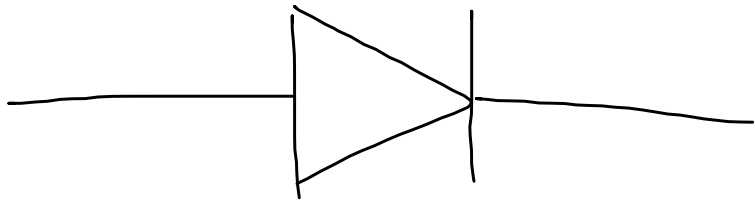


reversed-bias

depletion region

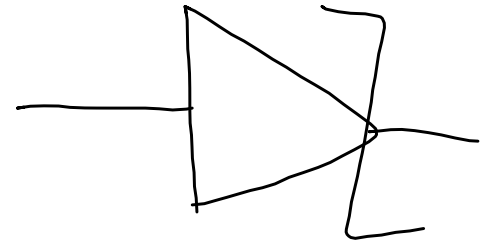


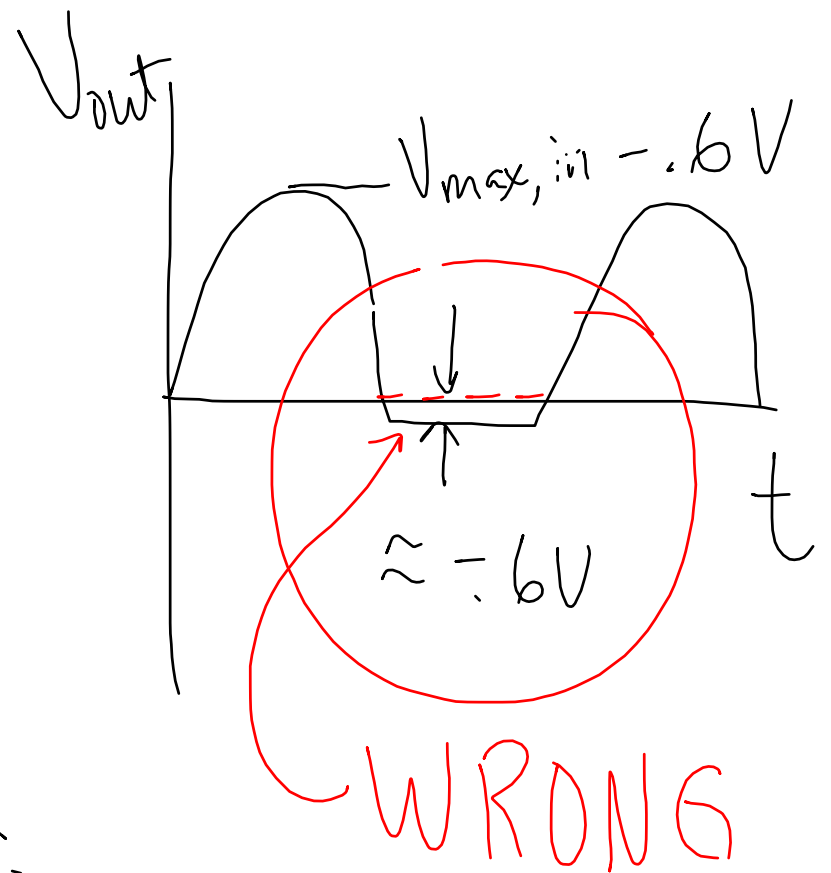
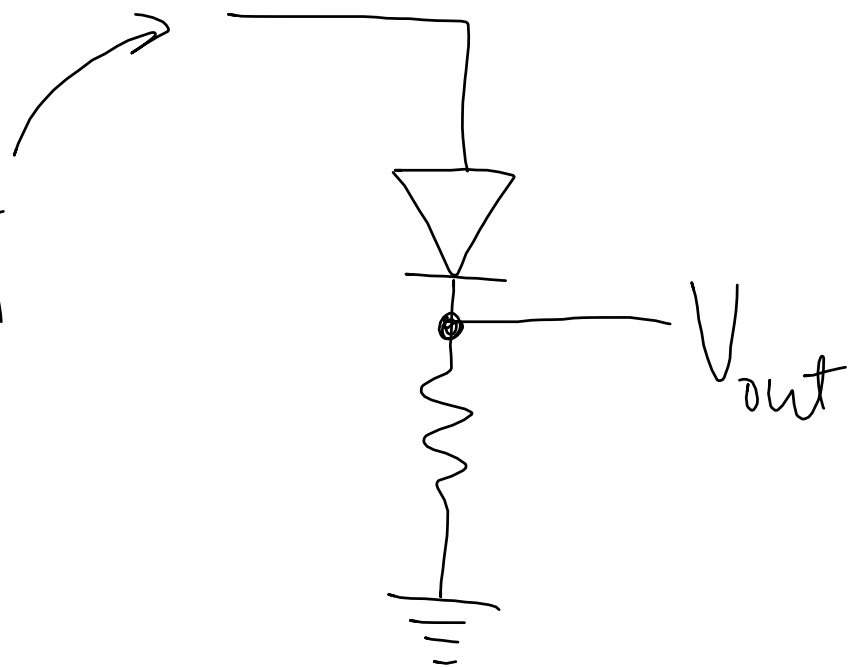
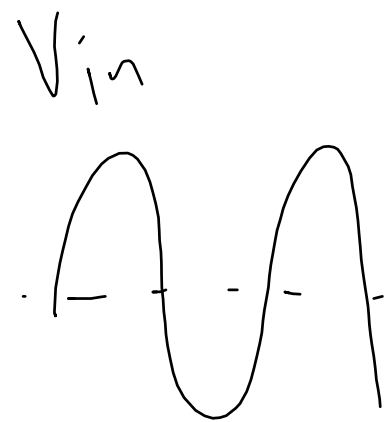
If $E_{\text{battery}} > E_d$
I get current
 \Rightarrow forward bias



If breakdown is intentional

\Rightarrow Zener diode





Half-wave rectifier

need full wave rectifier for best power

